

ATS277H

COMPLEMENTARY OUTPUT HALL EFFECT LATCH

Features

- On-Chip Hall Sensor with Two Different Sensitivity and Hysteresis Settings for ATS277H
- 3.5V to 20V Operating Voltage
- 400mA (avg.) Output Sink Current
- Built-in Protecting Diode Only for Chip Reverse Power Connecting
- -20°C to 85°C Operating Temperature
- Low Profile 4 Pin SIP Package
- Lead Free package: SIP-4L
- SIP-4L: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

General Description

ATS277H are integrated Hall sensors with output drivers, mainly designed for electronic commutation of brush-less DC Fan. This IC internally includes the regulator, protecting diode, Hall plate, amplifier, comparator, and a pair of complementary open-collector outputs (DO, DOB). While the magnetic flux density (B) is larger than operate point (Bop), DO will turn on (low), and meanwhile DOB will turn off (high). Each output is latched until B is lower than release point (Brp), and then DO,

DOB transfer each state.

For DC fan application, sometimes need to test power reverse connection condition. Internal diode only protects chip-side but not for coil-side. If necessary, add one external diode to block the reverse current from coil-side.

Applications

- Dual-Coil Brush-Less DC Motor
- Dual-Coil Brush-Less DC Fan
- Revolution Counting
- Speed Measurement

Ordering Information



		Baakaga	Packaging		Bulk	
	Device	Package Code	(Note 2)	Quantity	Part Number Suffix	Magnetic Characteristics
	ATS277H-PL-B-A	Р	SIP-4L	1000	-B	A
Pb	ATS277H-PL-B-B	Р	SIP-4L	1000	-B	В
Pb,	ATS277H-PG-B-A	Р	SIP-4L	1000	-B	A
Pb,	ATS277H-PG-B-B	Р	SIP-4L	1000	-B	В

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see *EU Directive 2002/95/EC Annex Notes*. 2. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

http://www.diodes.com/datasheets/ap02001.pdf. 3. Please refer to page 4 (Magnetic Characteristics table).



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Pin Assignments



Pin Descriptions

Pin Name	P/I/O	Pin #	Description
V _{cc}	Р	1	Power Supply Input
DO	0	2	Output Pin
DOB	0	3	Output Pin
GND	Р	4	Ground

Block Diagram





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Typical Application Circuit



Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

Symbol	Characterist	ics	Values	Unit	
V _{cc}	Supply Voltage		20	V	
V _{RCC}	Reverse V _{CC} Polarity Voltage	;	-20	V	
В	Magnetic Flux Density		Unlimited		
	Output "on" Current	Continuous	0.4		
lc		Hold	0.5	А	
		Peak (Start Up)	0.7		
Ts	Storage Temperature Range	Storage Temperature Range		С°	
P _D	Package Power Dissipation (Note 4)		550	mW	
TJ	Maximum Junction Tempera	ture	150	°C	

Note: 4. P_d shall be within Safety Operation Area.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage (Note 5)	Operating	3.5	20	V
T _A	Operating Ambient Temperature (Note 6)	Operating	-20	85	°C

Notes: 5. The output DO/DOB is switching as magnetic field change (S>300G, N<-300G). 6. Shall not exceed P_D and Safety Operation Area.



Electrical Characteristics ($T_A = +25^{\circ}C V_{cc} = 4.0V$ to 20V)

Symbol	Characteristic	Conditions	Min	Тур.	Max	Units
V _{ce}	Low Supply Voltage	$V_{cc} = 3.5V, I_{L} = 100mA$		0.4		V
Vz	Output Zener Breakdown	(Note 7)		46		V
V _{ce(SAT)}	Output Saturation Voltage	$V_{cc} = 14V, I_{L} = 300mA$		0.3	0.6	V
I _{cex}	Output Leakage Current	$V_{ce} = 14V, V_{cc} = 14V$		<0.1	10	μA
I _{cc}	Supply Current	V _{cc} = 20V, Output Open		16	25	mA
tr	Output Rise Time	$V_{cc} = 14V, R_{L} = 820\Omega, C_{L} = 20pF$		3.0	10	μs
tf	Output Falling Time	$V_{cc} = 14V, R_{L} = 820\Omega, C_{L} = 20pF$		0.3	1.5	μs
Δt	Switch Time Differential	$V_{cc} = 14V, R_{L} = 820\Omega, C_{L} = 20pF$		3.0	10	μs

Note: 7. The Vz may vary with the inductance/resistance of DC Fan. In order to reduce the risk of dynamic operation, the capacitor/ resistor is recommended to add below the DO/DOB as Application Circuit (see General Description on page 1).

Test Circuit



Magnetic Characteristics (T_A = +25°C)

(1mT = 10 Gauss)

A grade									
Symbol	Characteristic	Min	Тур.	Max	Unit				
Вор	Operate Point	10	-	50	Gauss				
Brp	Release Point	-50	-	-10	Gauss				
Bhy	Hysteresis	-	75	-	Gauss				

B grade

Symbol	Characteristic	Min	Тур.	Max	Unit
Вор	Operate Point	5	-	70	Gauss
Brp	Release Point	-70	-	-5	Gauss
Bhy	Hysteresis	-	75	-	Gauss



Magnetic Characteristics (Continued)



Operating Characteristics





Performance Characteristics

T _A (°C)	25	50	60	70	80	85	90	95	100
P _D (mW)	550	440	396	352	308	286	264	242	220
Т _А (°С)	105	110	115	120	125	130	135	140	150
P _D (mW)	198	176	154	132	110	88	66	44	0









Marking Information



Package Information (All Dimensions in mm)



Package Sensor Location



Package Dimension





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